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Publication date:
2018

Document Version
Publisher's PDF, also known as Version of record

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Citation (APA):

Spliid, F., Ammar, A., & Knott, A. (2018). *Stacked class E resonant Very High Frequency converter for European mains power factor correction*. Poster session presented at 6th International Workshop on Power Supply-On-Chip, Hsinchu, Taiwan, Province of China.

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Stacked class E resonant Very High Frequency converter for European mains power factor correction



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Introduction

- Great demand for compact PFCs in LED products.
- Driver size can be reduced by increasing switching frequency.
- This poster: design of 50 W resonant VHF AC/DC converter

Design

- Stacked configuration reduce voltage stresses and improve efficiency. [1]
- Class E inverter and class DE rectifier enables zero-voltage switching.

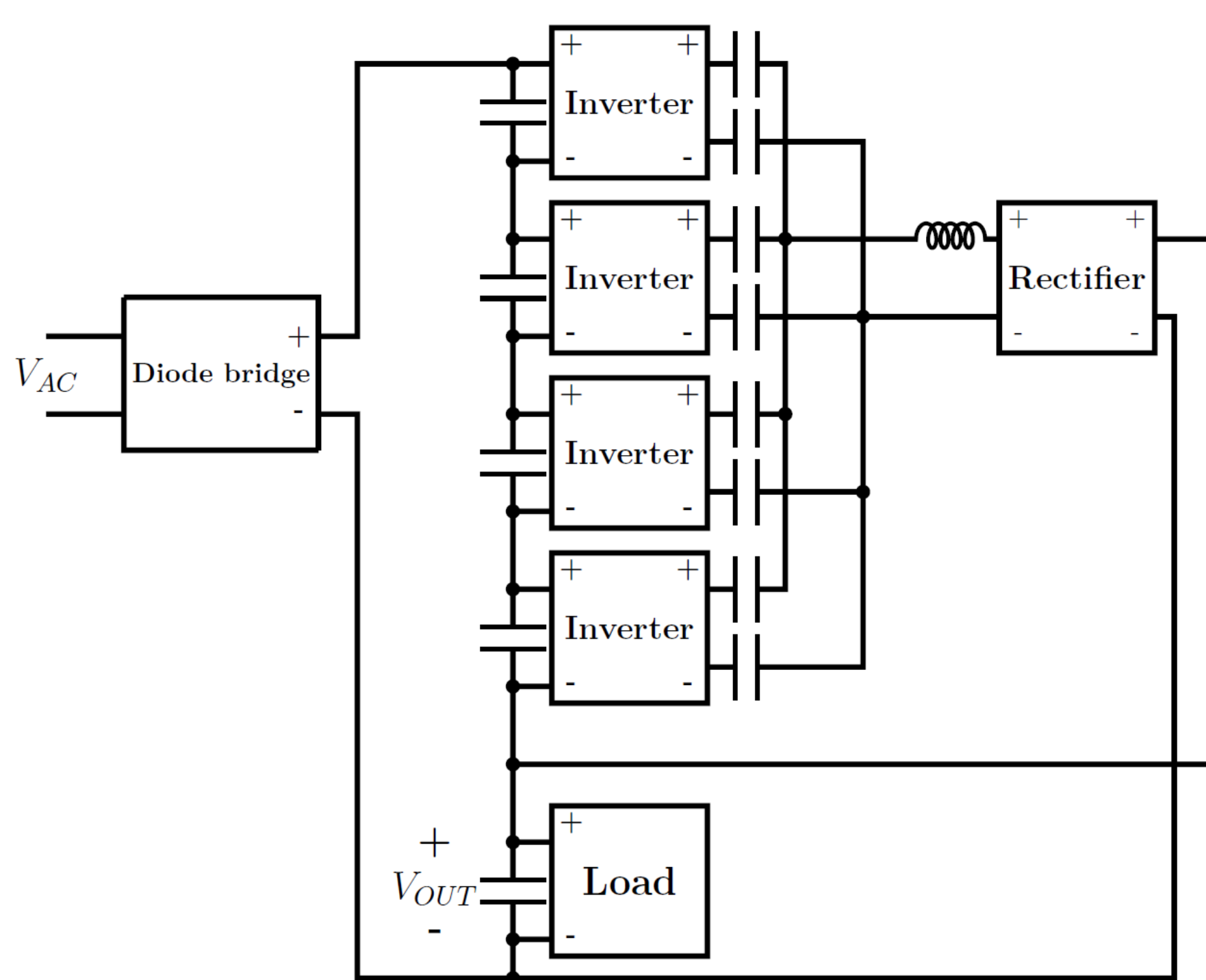


Fig. 1 Stacking configuration.

- GaN devices with low parasitic capacitance enable high switching frequency.
- Air-core inductors gives high Q magnetics at high frequencies.
- Self-resonant gate driver enables VHF switching [2].

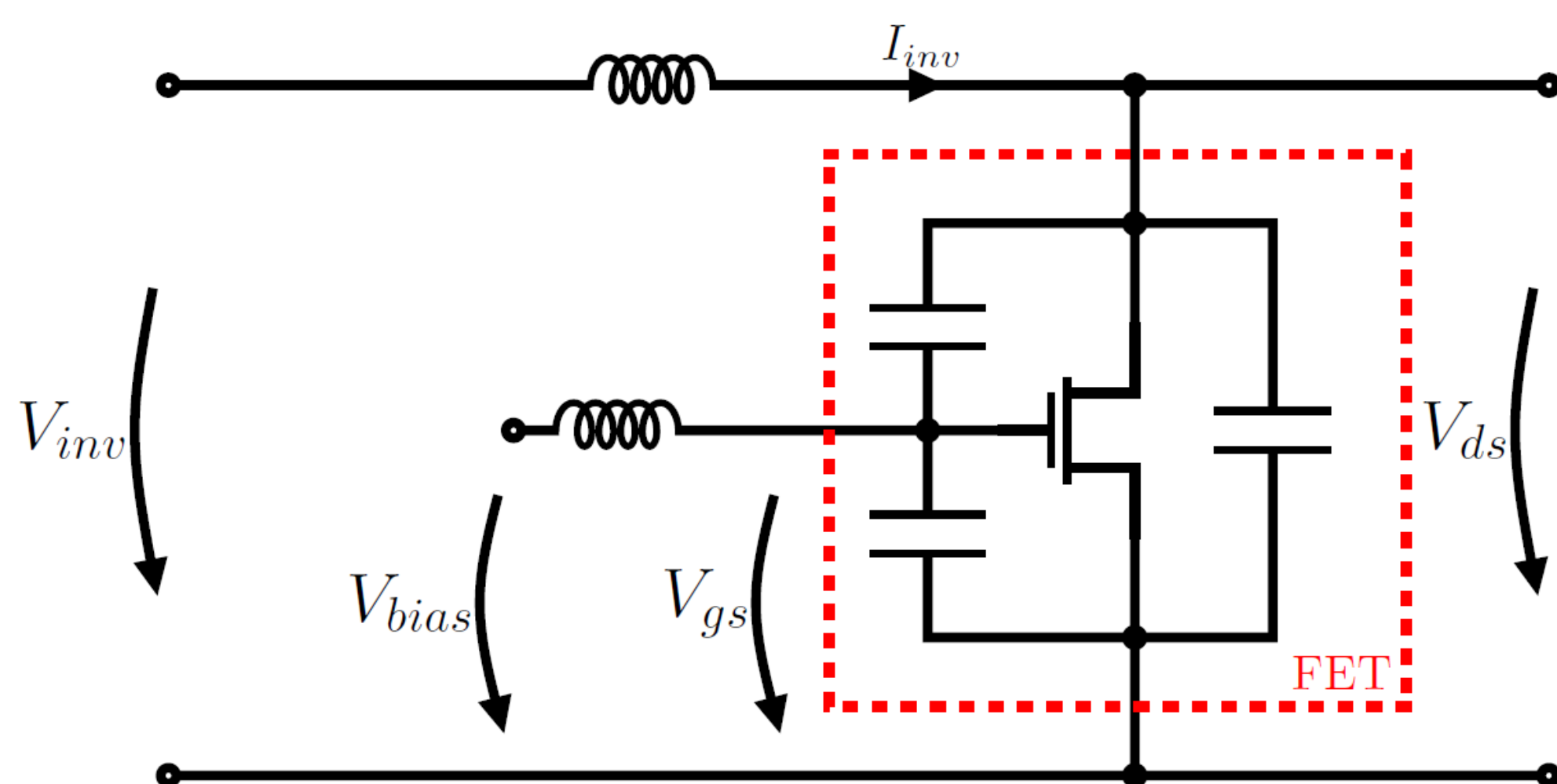


Fig. 2 Class E inverter stage with self-oscillating resonant gate drive

Input voltage	230 V _{AC} @ 50 Hz
Output voltage	110 V _{DC}
Switching frequency	30-37 MHz

Tab. 1 Converter specifications

Simulation performance

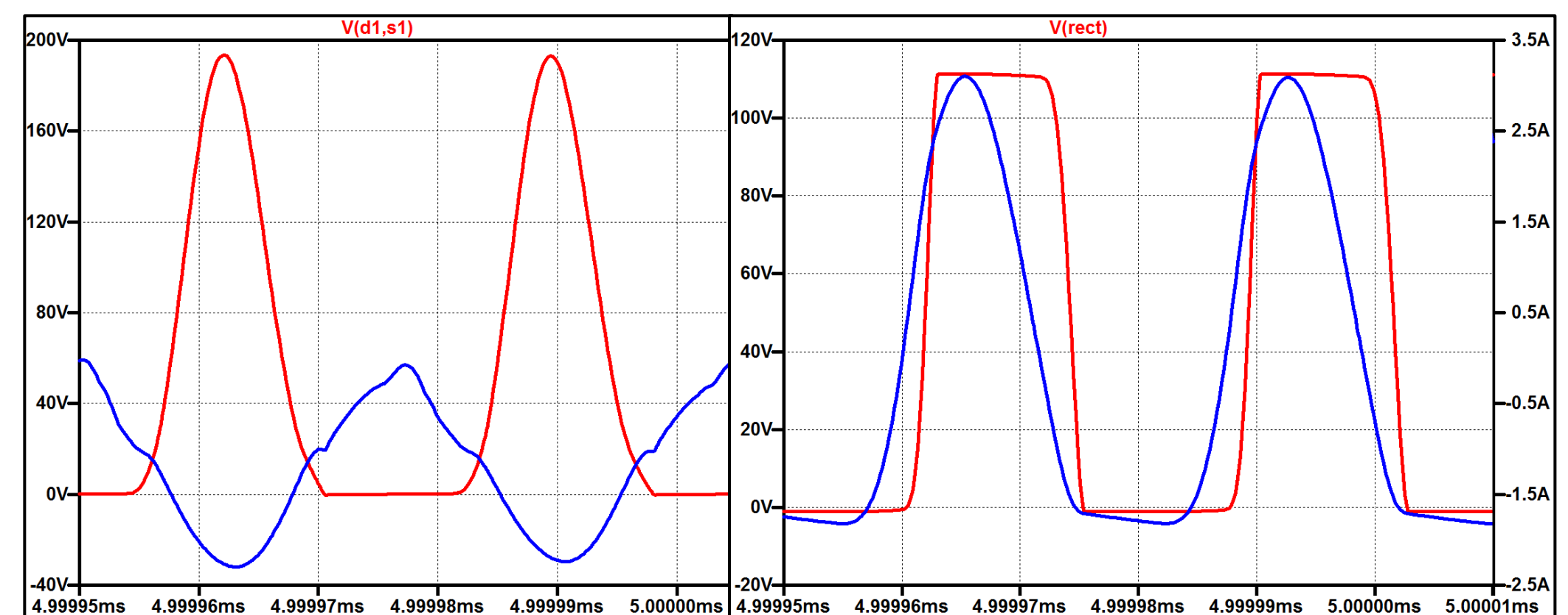


Fig. 3 Left: V_{ds} (red) and 10x scaled V_{gs} (blue) of inverter switch
Right: Rectifier input voltage (red) and current (blue)

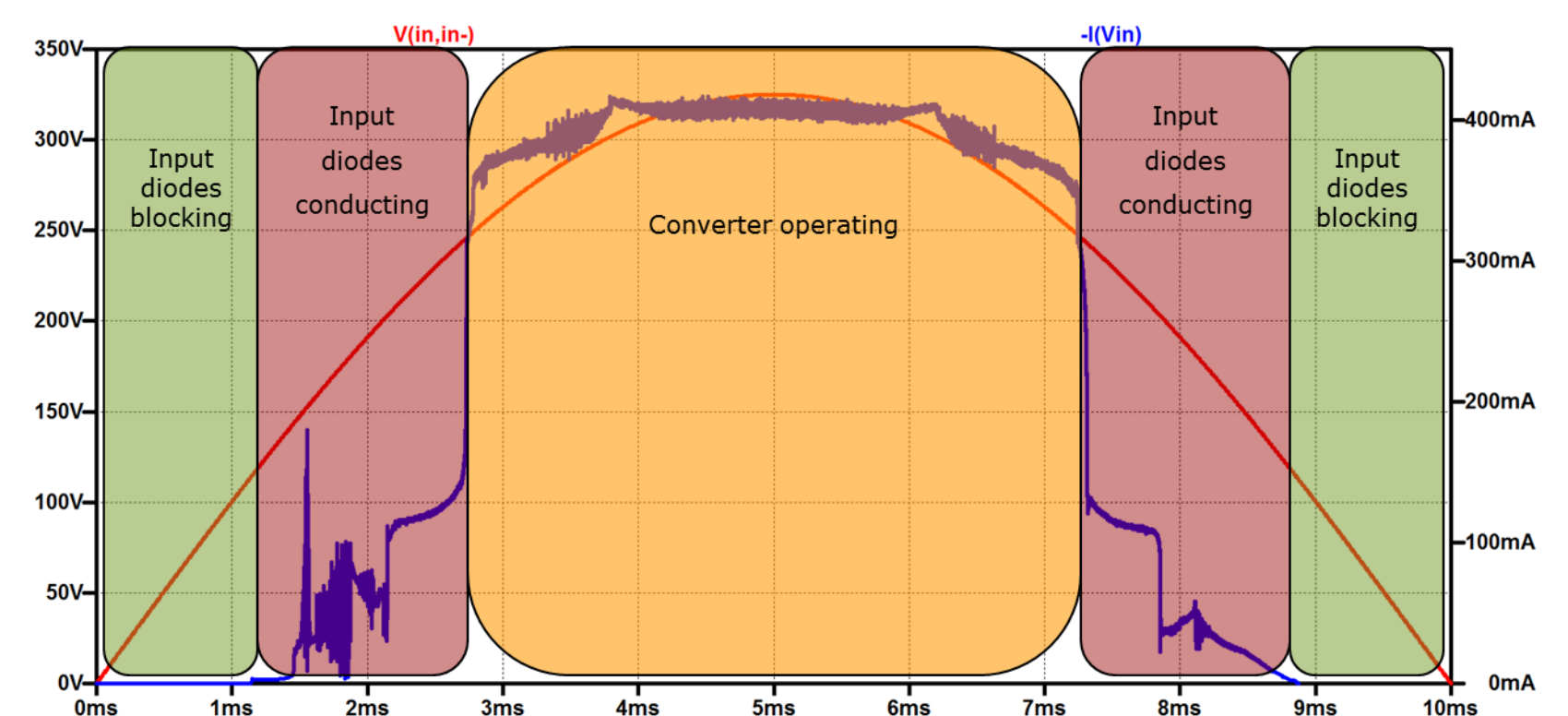


Fig. 4 Input voltage (red) and current (blue)

Output power	52.2 W
Efficiency	90.3 %
Power Factor	93 %
Input current THD	38 %

Tab. 2 Simulated converter performance

Conclusion

- Stacked topology reduce voltage stresses.
- GaN transistors and air-core inductors enable VHF operation
- Self-oscillating gate drive enables open-loop operation

References

- [1] M. Madsen et al., "Input-Output Rearrangement of Isolated Converters", in *Proceedings of 2015 IEEE Power and Energy Conference at Illinois, 2015*.
- [2] M. Madsen et al., "Self-oscillating resonant gate drive for resonant inverters and rectifiers composed solely of passive components", in *Twenty-Ninth Annual IEEE Applied Power Electronics Conference and Exposition (APEC), 2014*.
- [3] J. Pedersen et al., "US Mains Stacked Very High Frequency Self-oscillating Resonant Power Converter with Unified Rectifier", in *Thirty-first Annual IEEE Applied Power Electronics Conference and Exposition (APEC), 2016*

Acknowledgement



This project has received funding from the European Union's Horizon 2020 research and innovation programme under grant agreement No 731466